MCR264-4, MCR264-6, MCR264-8

Preferred Device

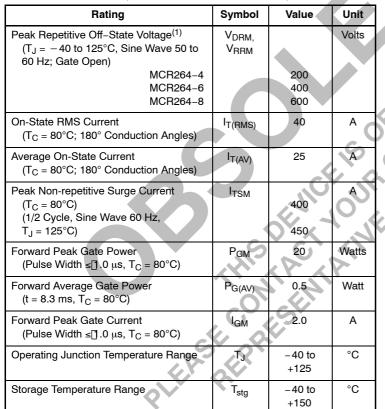
Silicon Controlled Rectifiers

Reverse Blocking Thyristors

Designed for back-to-back SCR output devices for solid state relays or applications requiring high surge operation.

- Photo Glass Passivated Blocking Junctions for High Temperature Stability, Center Gate for Uniform Parameters
- 400 Amperes Surge Capability
- Blocking Voltage to 600 Volts
- Device Marking: Logo, Device Type, e.g., MCR264-4, Date Code

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)



(1) V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

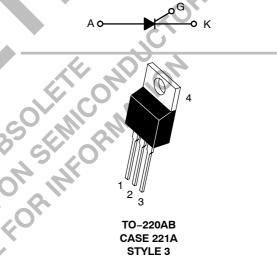
These devices are rated for use in applications subject to high surge conditions. Care must be taken to insure proper heat sinking when the device is to be used at high sustained currents.



ON Semiconductor

http://onsemi.com

SCRs 40 AMPERES RMS 200 thru 600 VOLTS



PIN ASSIGNMENT				
1	Cathode			
2	Anode			
3	Gate			
4	Anode			

ORDERING INFORMATION

Device	Package	Shipping		
MCR264-4	TO220AB	500/Box		
MCR264-6	TO220AB	500/Box		
MCR264-8	TO220AB	500/Box		

Preferred devices are recommended choices for future use and best overall value.

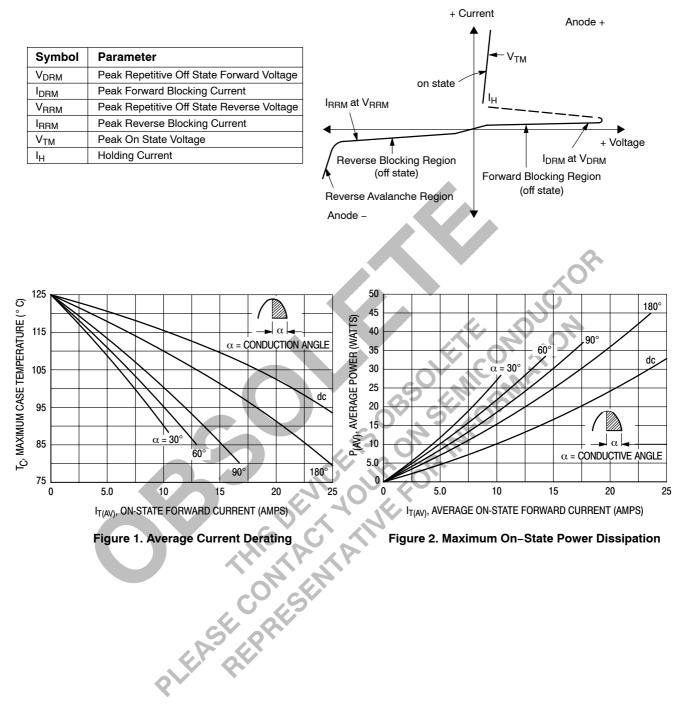
MCR264-4, MCR264-6, MCR264-8

THERMAL CHARACTERISTICS

Characteristic			Max		Unit	
Thermal Resistance, Junction to Case		$R_{\theta JC}$	1.0		°C/W	
Thermal Resistance, Junction to Ambient		$R_{\theta JA}$	60		°C/W	
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds		TL	260		°C	
ELECTRICAL CHARACTERISTICS (T _C = 25°C unless otherwise noted	d.)					
Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS					-	
$\begin{array}{l} \mbox{Peak Repetitive Forward or Reverse Blocking Current} \\ (V_{AK} = Rated V_{DRM} \mbox{ or } V_{RRM}, \mbox{ Gate Open}) & T_J = 25^{\circ}\mbox{C} \\ T_J = 125^{\circ}\mbox{C} \end{array}$	I _{DRM} , I _{RRN}	л —		10 2.0	μA mA	
ON CHARACTERISTICS						
Peak Forward On-State Voltage ⁽¹⁾ (I _{TM} = 80 A)	V _{TM}		1.4	2.0	Volts	
Gate Trigger Current (Continuous dc) (V_{AK} = 12 Vdc, R_L = 100 Ohms, T_C = - 40°C)	lgt		15 30	50 90	mA	
Gate Trigger Voltage (Continuous dc) (V _{AK} = 12 Vdc, R _L = 100 Ohms)	V _{GT}	_	1.0	1.5	Volts	
Gate Non-Trigger Voltage (V _{AK} = 12 Vdc, R _L = 100 Ohms, T _J = 125°C)	V _{GD}	0.2	0_0		Volte	
Holding Current (V _{AK} = 12 Vdc, Initiating Current = 200 mA, Gate Open)	Ц	G	30	60	mA	
Turn-On Time (I _{TM} = 40 A, I _{GT} = 60 mAdc)	t _{gt}		1.5		μs	
OYNAMIC CHARACTERISTICS		1				
Critical Rate-of-Rise of Off-State Voltage (Gate Open, V _D = Rated V _{DRM} , Exponential Waveform)	dv/dt	-	50		V/µs	
(ITM = 40 A, IGT = 60 IMAde) DYNAMIC CHARACTERISTICS Critical Rate-of-Rise of Off-State Voltage (Gate Open, V _D = Rated V _{DRM} , Exponential Waveform) I) Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.						

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Voltage Current Characteristic of SCR



MCR264-4, MCR264-6, MCR264-8

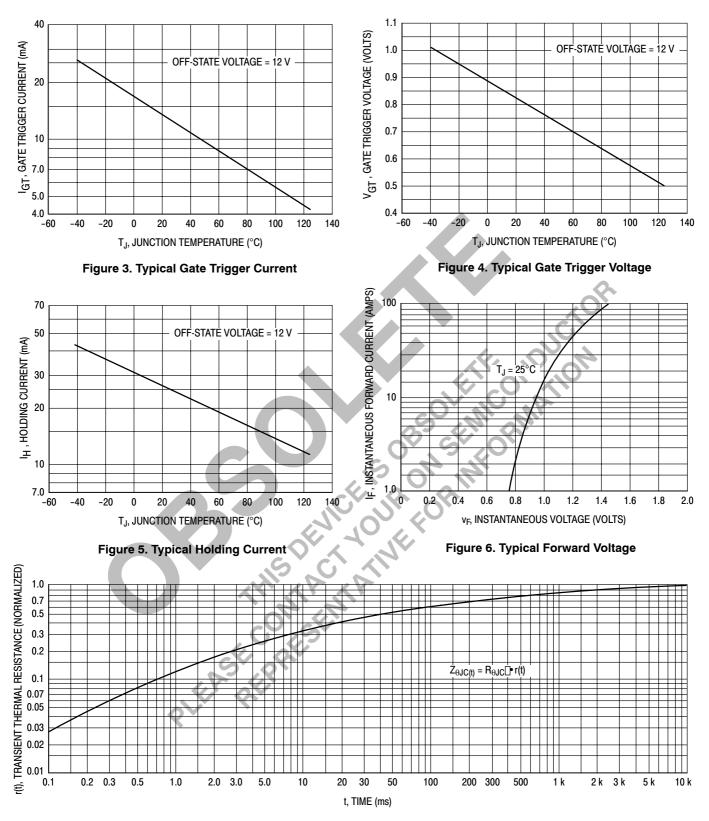
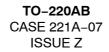
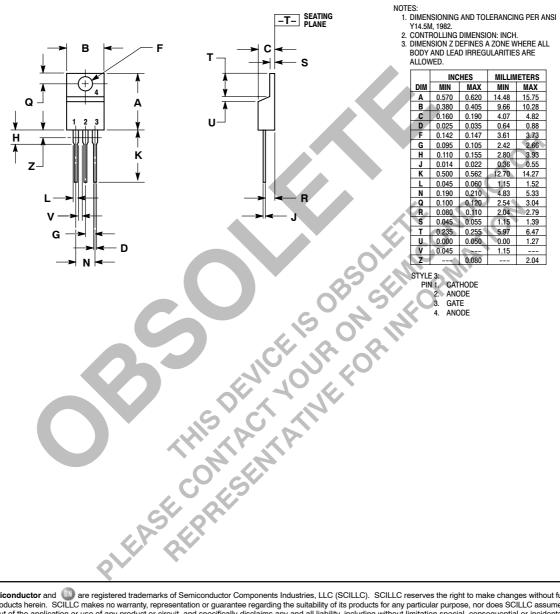


Figure 7. Thermal Response

PACKAGE DIMENSIONS





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